TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type

SSM3K123TU

Power Management Switch Applications High-Speed Switching Applications

1.5 V drive

Low ON-resistance: $R_{on} = 66 \text{ m}\Omega \text{ (max)} (@V_{GS} = 1.5 \text{ V})$

 $R_{on} = 43 \text{ m}\Omega \text{ (max)} (@V_{GS} = 1.8 \text{ V})$

 $R_{on} = 32 \text{ m}\Omega \text{ (max)} (@V_{GS} = 2.5 \text{ V})$

 $R_{on} = 28 \text{ m}\Omega \text{ (max)} (@V_{GS} = 4.0 \text{ V})$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DSS}	20	V	
Gate-Source voltage		V _{GSS}	± 10	V	
Drain current	DC	I _D	4.2	A	
	Pulse	I _{DP}	8.4		
Drain power dissipation		PD (Note 1)	800	mW	
		PD (Note 2)	500		
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on a ceramic board. (25.4 mm \times 25.4 mm \times 0.8 t, Cu Pad: 645 mm²)

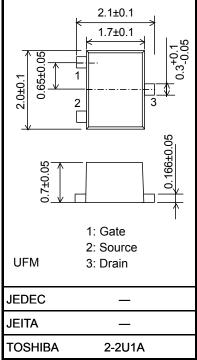
Note 2: Mounted on a FR4 board. (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 645 mm²)

Electrical Characteristics (Ta = 25°C)

Charact	eristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Drain-Source breakdown voltage	V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0V$ $I_D = 1 \text{ mA}, V_{GS} = -10 \text{ V}$		20	—		V	
	V (BR) DSX			12	—			
Drain cutoff curren	t	IDSS	$V_{DS} = 20 V, V_{GS} = 0V$			—	1	μA
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{V}$			—	±1	μA
Gate threshold vol	tage	V _{th}	$V_{DS} = 3 V, I_D = 1 mA$		0.35	—	1.0	V
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = 3 V, I_D = 3.0 A$	(Note 3)	12.5	25		S
Drain-Source ON-resistance	R _{DS} (ON)	$I_D = 3.0 \text{ A}, V_{GS} = 4.0 \text{ V}$	(Note 3)	—	19	28	mΩ	
		$I_D = 3.0 \text{ A}, V_{GS} = 2.5 \text{ V}$	(Note 3)		23	32		
		I _D = 1.0 A, V _{GS} = 1.8 V	(Note 3)		28	43		
		I _D = 0.5 A, V _{GS} = 1.5 V	(Note 3)		35	66		
Input capacitance		C _{iss}				1010		
Output capacitance		C _{oss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz			162		pF
Reverse transfer capacitance		C _{rss}				150		
Total Gate Charge Gate–Source Charge		Qg	V _{DS} = 10 V, I _{DS} = 4.2 A, V _{GS} = 4 V			13.6		nC
		Q _{gs}				9.8		
Gate-Drain Charge		Q _{gd}			_	3.8		
Switching time	Turn-on time	t _{on}	$V_{DD} = 10 \text{ V}, \text{ I}_{D} = 1.0 \text{ A},$		_	17	_	
	Turn-off time	t _{off}	V_{GS} = 0 to 2.5 V, R_{G} = 4.7 Ω		_	30	_	ns
Drain-Source forward voltage		V _{DSF}	$I_D = -4.2 \text{ A}, V_{GS} = 0 \text{ V}$	(Note 3)	—	- 0.8	- 1.2	V

Note 3: Pulse test

Start of commercial production 2007-04



Weight: 6.6 mg (typ.)

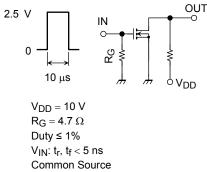
Unit: mm

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Switching Time Test Circuit

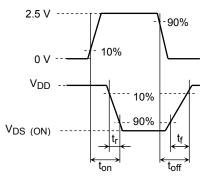
(a) Test Circuit

(b) V_{IN}

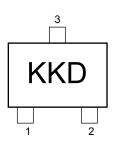


 $Ta = 25^{\circ}C$

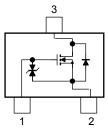
(c) V_{OUT}



Marking



Equivalent Circuit (top view)



Notice on Usage

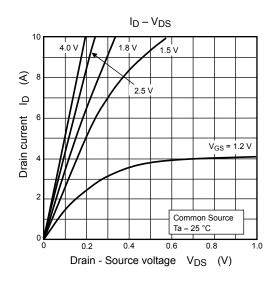
 V_{th} can be expressed as the voltage between gate and source when the low operating current value is $I_D = 1$ mA for this product. For normal switching operation, $V_{GS (on)}$ requires a higher voltage than V_{th} , and $V_{GS (off)}$ requires a lower voltage than V_{th} . (The relationship can be established as follows: $V_{GS (off)} < V_{th} < V_{GS (on)}$.)

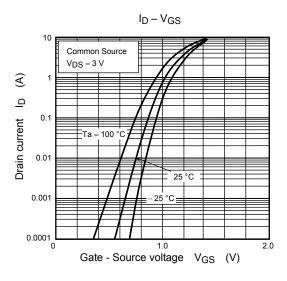
Take this into consideration when using the device.

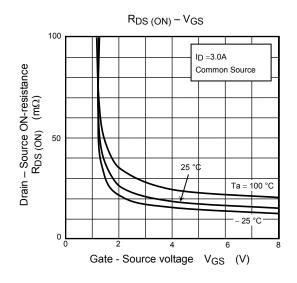
Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

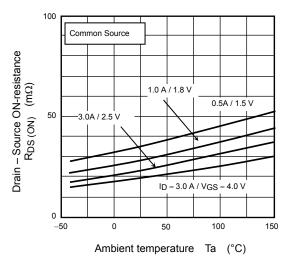
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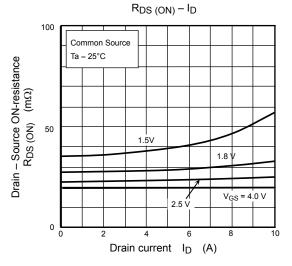


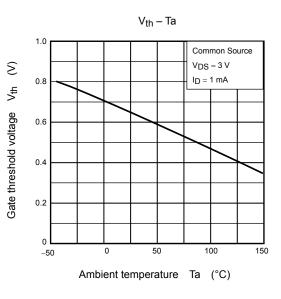




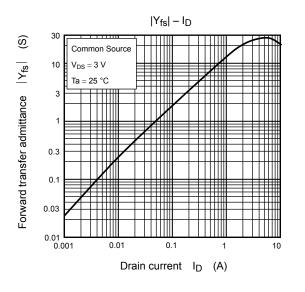


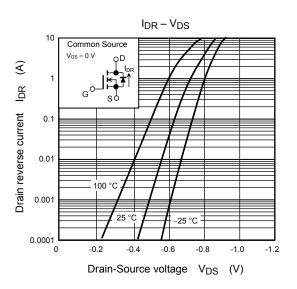


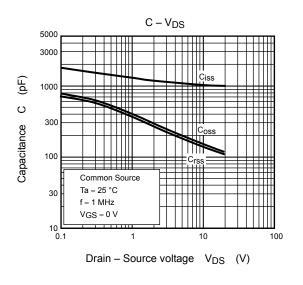


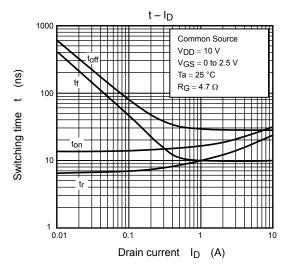


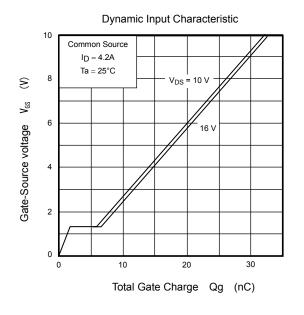
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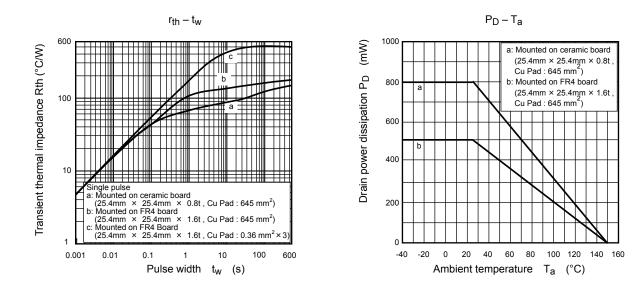












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